

DESCRIPTION

The H710 is designed for use with the M177 in a parallel-serial system. It is also possible to construct a 10-Bit DAC using two H710's. The hybrid contains Nichrome resistors with a sheet resistance of $50 \Omega/\text{sq.}$. R_P sets the reference current and is trimmed to $480 \Omega/\text{sq.}$. R_A is a pull-up load resistor trimmed to be $0.25 R_P$. Binarily-scaled emitter resistors are functionally trimmed to set-up precision current sources. These are trimmed while measuring the output current at Pin #5. Two unswitched current sources approximately equal to 1LSB are provided. One is connected to the output, the other is available as an open collector. The emitters of these two current sources are brought out so that they can be adjusted or disabled.

The part is designed to operate with a reference of +3.072 volts or ± 1.536 volts. Full scale output current is then 25.6 mA. A -5.2 volt digital supply is needed to set-up the reference current. Digital inputs are ECL compatible and sink 1 mA each.

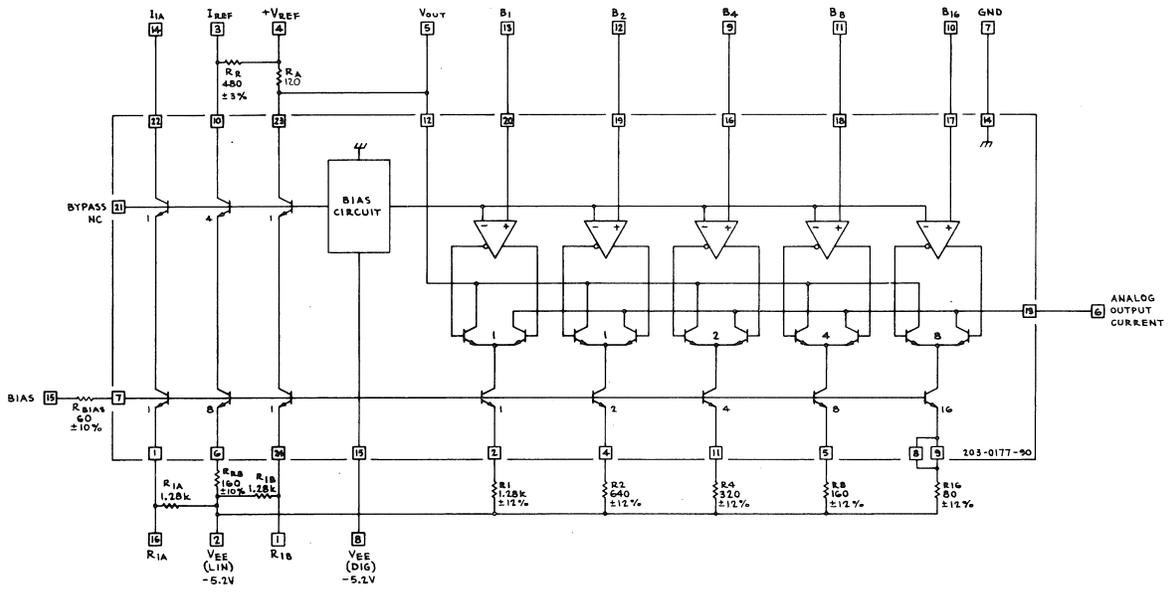
The H710 is tested to have linearity between $\pm 0.05\%$ ($\pm 1/2$ LSB at 10 bits). More specifically, the four LSB currents ratio binarily to the MSB current within $\pm 0.05\%$ of full scale where full scale is defined to be twice the MSB current. Differential non-linearity is also tested so that each 1-bit transition causes an output change of $1/32$ of full scale $\pm 0.05\%$ full scale. A final check of overall linearity is made by testing that the sum of the absolute values of each bit current error is less than 0.1% of full scale. This guarantees an overall non-linearity of less than $\pm 0.05\%$.

The trimming and testing of the hybrid is done with the output at a constant potential in order to minimize non-linearity due to variable DAC output conductance. Theory and some testing indicate that an output compliance of 3 volts will affect linearity in a "smooth" fashion by less than 0.05% of full scale.

Settling time to $\pm 1/2$ LSB with 10 pF load capacitance is typically 15 nS for 8-bits.

Refer to 203-0177-90 M177

PROCESS	Thin-Film
POWER SUPPLY.	
PACKAGE	T0-8
DESIGNER	Bob Nordstrom
INSTRUMENT USAGE	ADC 820



- NOTES:**
1. R_k IS TRIMMED SO THAT $V(\text{PIN } 10) = -750\text{mV} \pm 50\text{mV}$.
 2. R_A IS TRIMMED TO RATIO TO R_k .
 3. R_{1A} , R_{1B} , R_{1C} AND R_{16} ARE TRIMMED SO THAT THEIR RESPECTIVE OUTPUT CURRENTS SCALE APPROXIMATELY TO THE REFERENCE CURRENT.
 4. R_1 , R_2 AND R_4 ARE TRIMMED SO THAT THEIR RESPECTIVE OUTPUT CURRENTS SCALE ACCURATELY TO THE CURRENT THROUGH R_8 .
 5. FOR RATIO AND SCALING TOLERANCE SEE LASER TRIM SPECIFICATION.

ENGR	<i>[Signature]</i>	4-29-77	PROCESS	
DWN BY	<i>[Signature]</i>	4-21-77	PACKAGE	16PIN TO-8 LG.
CHK BY	<i>[Signature]</i>	5-26-77	SUB SIZE	3" X 3"
TYPE	HYBRID			H710
INTEGRATED CIRCUIT DIV./MFG			TEKTRONIX, INC.	
BEAVERTON, OREGON, U.S.A.			PART NO. 155-0167-01	

OUTLINE DRAWING NOT AVAILABLE AT THIS TIME